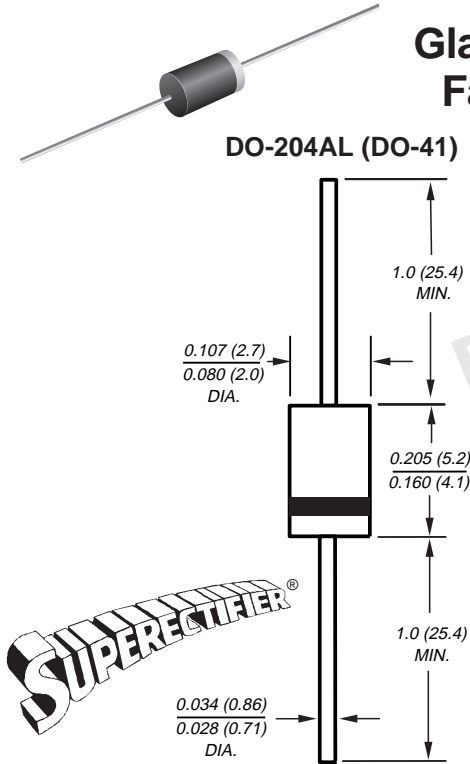




Glass Passivated Junction Fast Switching Rectifier

Reverse Voltage 400 to 1000 V
Forward Current 1.0 A



NOTE: Lead diameter is $\frac{0.026 (0.66)}{0.023 (0.58)}$ for suffix "E" part numbers

Dimensions in inches and (millimeters)

*Glass-plastic encapsulation technique is covered by

Patent No. 3,996,602, and brazed-lead assembly by Patent No. 3,930,306

Features

- Plastic package has Underwriters Laboratories Flammability Classification 94V-0
- High temperature metallurgically bonded construction
- For use in high frequency rectifier circuits
- Fast switching for high efficiency
- Cavity-free glass passivated junction
- Capable of meeting environmental standards of MIL-S-19500
- 1.0 Ampere operation at $T_A=55^\circ\text{C}$ with no thermal runaway
- Typical I_R less than $0.1\mu\text{A}$
- High temperature soldering guaranteed: $350^\circ\text{C}/10$ seconds, $0.375"$ (9.5mm) lead length, 5 lbs. (2.3kg) tension

Mechanical Data

Case: JEDEC DO-204AL, molded plastic over glass body

Terminals: Plated axial leads, solderable per MIL-STD-750, Method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any

Weight: 0.012 ounce, 0.3 gram

Maximum Ratings & Thermal Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbols	BA157GP	BA158GP	BA159DGP	BA159GP	Units
Maximum repetitive peak reverse voltage	V_{RRM}	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	400	600	800	1000	V
Maximum average forward rectified current $0.375"$ (9.5mm) lead length at $T_A=55^\circ\text{C}$	$I_{F(AV)}$	1.0				A
Peak forward surge current 10ms single half sine-wave superimposed on rated load at $T_A=25^\circ\text{C}$	I_{FSM}	20				A
Typical thermal resistance (NOTE 1)	$R_{\theta JA}$	55				$^\circ\text{C}/\text{W}$
Operating junction and storage temperature range	T_J, T_{STG}	- 65 to +175				$^\circ\text{C}$

Electrical Characteristics Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbols	BA157GP	BA158GP	BA159DGP	BA159GP	Units
Maximum instantaneous forward voltage at 1.0A	V_F	1.3				V
Maximum DC reverse current at rated DC blocking voltage $T_A=25^\circ\text{C}$	I_R	5.0				μA
Maximum reverse recovery time at $I_F=0.5\text{A}$, $I_R=1.0\text{A}$, $I_{rr}=0.25\text{A}$	t_{rr}	150	250	500	500	ns
Typical junction capacitance at 4.0V, 1MHz	C_J	15				pF

Notes:

(1) Thermal resistance from junction to ambient at $0.375"$ (9.5mm) lead length, P.C.B. mounted

BA157GP thru BA159GP



Vishay Semiconductors
formerly General Semiconductor

Ratings and Characteristic Curves ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Fig. 1 – Forward Current Derating Curve

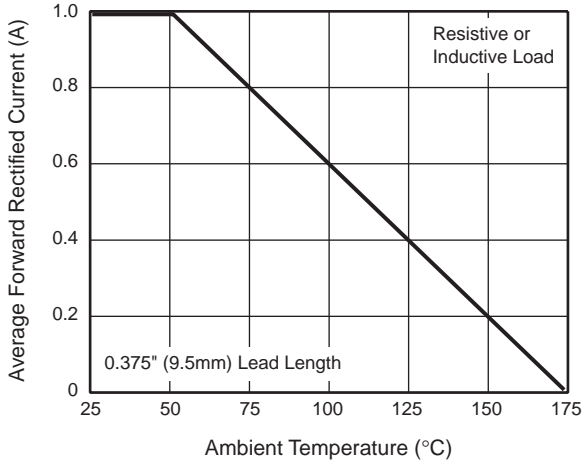


Fig. 2 – Maximum Non-Repetitive Peak Forward Surge Current

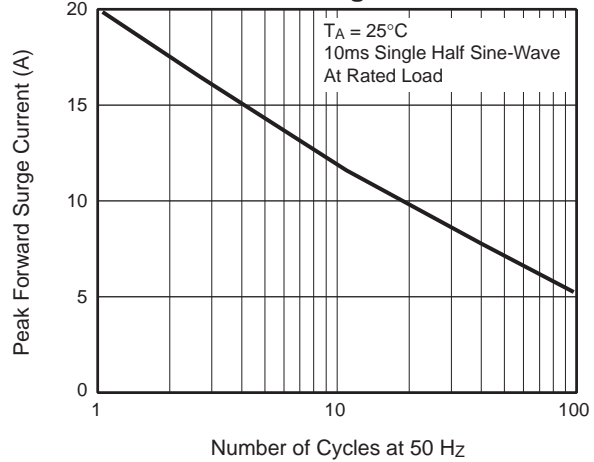


Fig. 3 – Typical Instantaneous Forward Characteristics

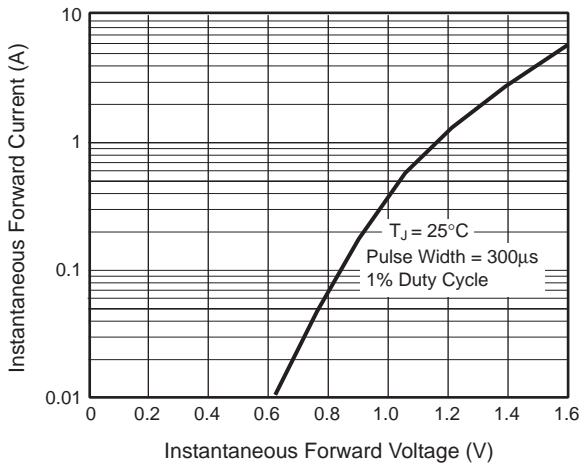


Fig. 4 – Typical Reverse Characteristics

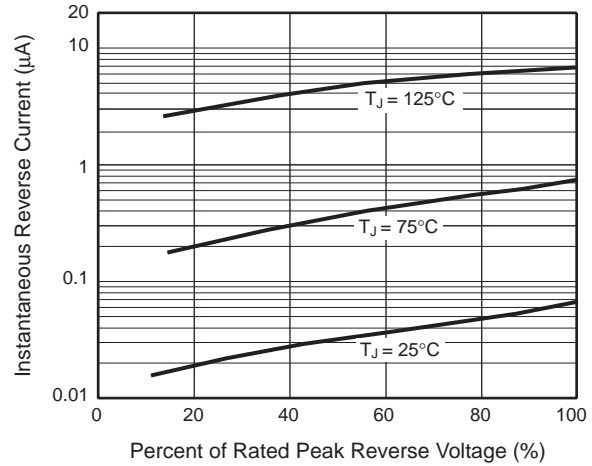


Fig. 5 – Typical Junction Capacitance

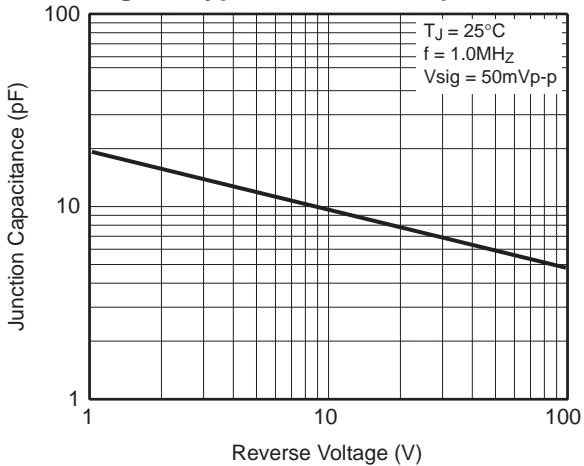
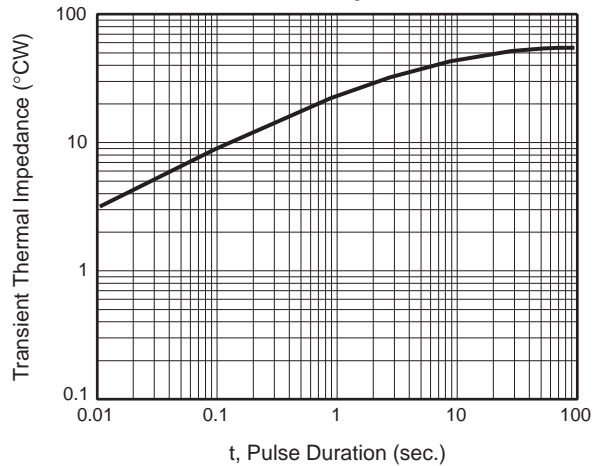


Fig. 6 – Typical Transient Thermal Impedance





LittleDiode supplies new, hard to find or obsolete electronic components and semiconductors all over the world.

With over two million different components listed you are sure to find the part you need.

Feel free to visit us today at our online store:

LittleDiode.com

Looking forward to providing you with the best possible service.